

'D	Drain Current - Continuous ($T_{C} = 25$	0)	I
	- Continuous (T _C = 100)°C)	0.6
I _{DM}	Drain Current - Pulsed	(Note 1)	4
V _{GSS}	Gate-Source Voltage		± 30
E _{AS}	Single Pulsed Avalanche Energy	(Note 2)	33
I _{AR}	Avalanche Current	(Note 1)	1
E _{AR}	Repetitive Avalanche Energy	(Note 1)	2.8
dv/dt	Peak Diode Recovery dv/dt (Note 3)		4.5
	Power Dissipation (T _A = 25°C)*		2.5
PD	Power Dissipation (T _C = 25°C)		28
	- Derate above 25°C		0.22

T _J , T _{STG}		Operating and Storage Temperature Range	
	ΤL	Maximum lead temperature for soldering purposes, 1/8" from case for 5 seconds	

Thermal Characteristics

Symbol	Parameter	Тур	Max	Units
$R_{\theta JC}$	Thermal Resistance, Junction-to-Case		4.53	°C/W
R_{\thetaJA}	Thermal Resistance, Junction-to-Ambient*		50	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient		110	°C/W

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А

V

mJ

А

mJ V/ns

W

W W/°C

°C

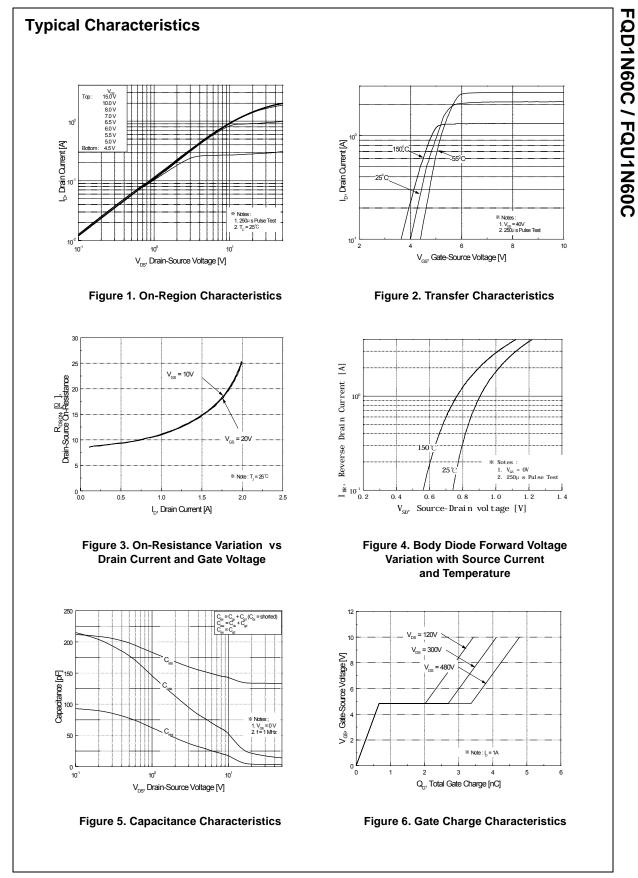
°C

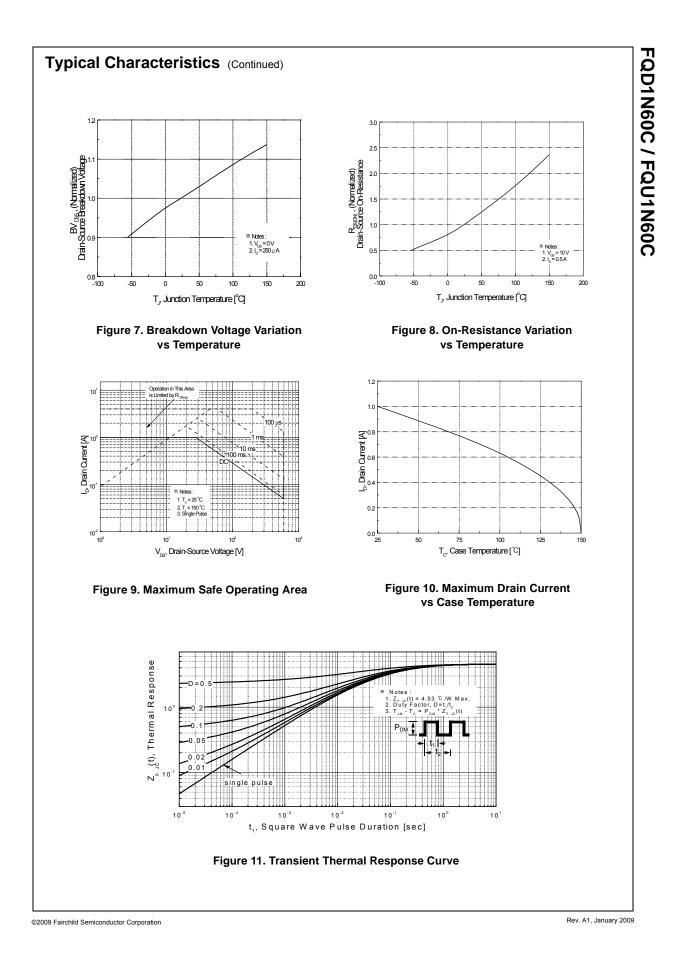
-55 to +150

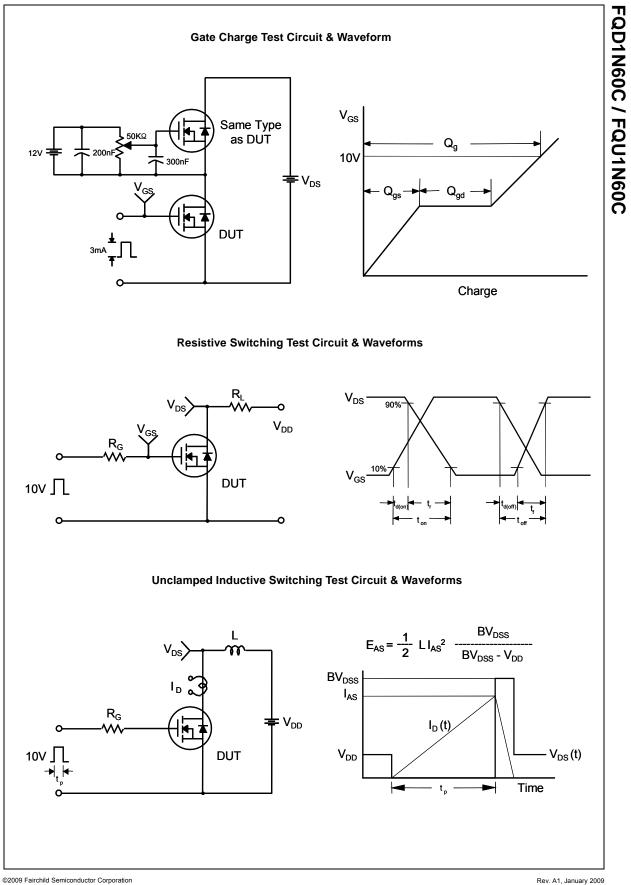
300

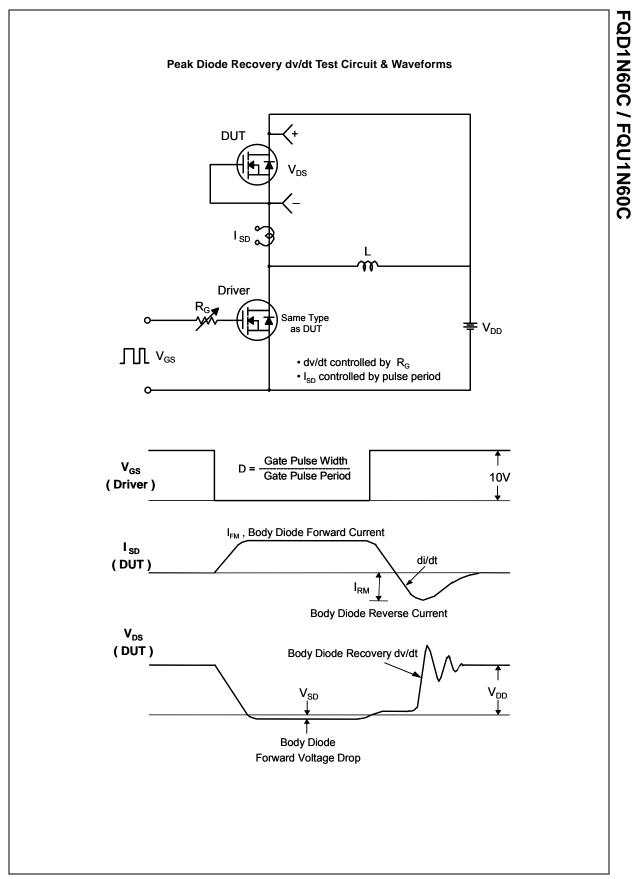
Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Off Cha	racteristics					
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} = 0 V, I _D = 250 μA	600			V
ΔBV_{DSS}	Breakdown Voltage Temperature		000			-
$/ \Delta T_{J}$	Coefficient	I_D = 250 µA, Referenced to 25°C		0.6		V/°C
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} = 600 V, V _{GS} = 0 V		1	1	μA
		V _{DS} = 480 V, T _C = 125°C			10	μA
I _{GSSF}	Gate-Body Leakage Current, Forward	V_{GS} = 30 V, V_{DS} = 0 V			100	nA
I _{GSSR}	Gate-Body Leakage Current, Reverse	V_{GS} = -30 V, V_{DS} = 0 V			-100	nA
On Cha	racteristics					
V _{GS(th)}	Gate Threshold Voltage	V _{DS} = V _{GS} , I _D = 250 μA	2.0		4.0	V
R _{DS(on)}	Static Drain-Source On-Resistance	$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 0.5 \text{ A}$		9.3	11.5	Ω
9 _{FS}	Forward Transconductance	$V_{DS} = 40 \text{ V}, \text{ I}_{D} = 0.5 \text{ A}$ (Note 4)		0.75		S
-	I				1	
	ic Characteristics	1	r		1	
C _{iss}	Input Capacitance	V_{DS} = 25 V, V_{GS} = 0 V,		130	170	pF
C _{oss}	Output Capacitance	f = 1.0 MHz		19	25	pF
C _{rss}	Reverse Transfer Capacitance			3.5	4.5	pF
Switchi	ing Characteristics					
t _{d(on)}	Turn-On Delay Time			7	24	ns
t _r	Turn-On Rise Time	$V_{DD} = 300 \text{ V}, \text{ I}_{D} = 1.1 \text{ A},$ R _G = 25 Ω		21	52	ns
t _{d(off)}	Turn-Off Delay Time	ng - 23 32		13	36	ns
t _f	Turn-Off Fall Time	(Note 4, 5)		27	64	ns
Qg	Total Gate Charge	V _{DS} = 480 V, I _D = 1.1 A,		4.8	6.2	nC
Q _{gs}	Gate-Source Charge	$V_{GS} = 10 V$		0.7		nC
Q _{gd}	Gate-Drain Charge	(Note 4, 5)		2.7		nC
Drain-S	Source Diode Characteristics an Maximum Continuous Drain-Source Dio	ode Forward Current			1	A
I _{SM}	Maximum Pulsed Drain-Source Diode F				4	Α
V _{SD}	Drain-Source Diode Forward Voltage				1.4	V
t _{rr}	Reverse Recovery Time	$V_{GS} = 0 V, I_S = 1.1 A,$		190		ns
Q _{rr}	Reverse Recovery Charge	$dI_F / dt = 100 \text{ A}/\mu \text{s}$ (Note 4)		0.53		μC
L = 59 mH $I_{SD} \le 1.1$ A, Pulse Test :	ating : Pulse width limited by maximum junction tempe I, I _{AS} = 1.1 A, V _{DD} = 50V, R _G = 25 Ω , Starting T _J = 25 di/dt ≤ 200 A/µs, V _{DD} $\leq B$ V _{DSS} , Starting T _J = 25°C Pulse width ≤ 300 µs, Duty cycle $\leq 2\%$ ndependent of operating temperature					

FQD1N60C / FQU1N60C

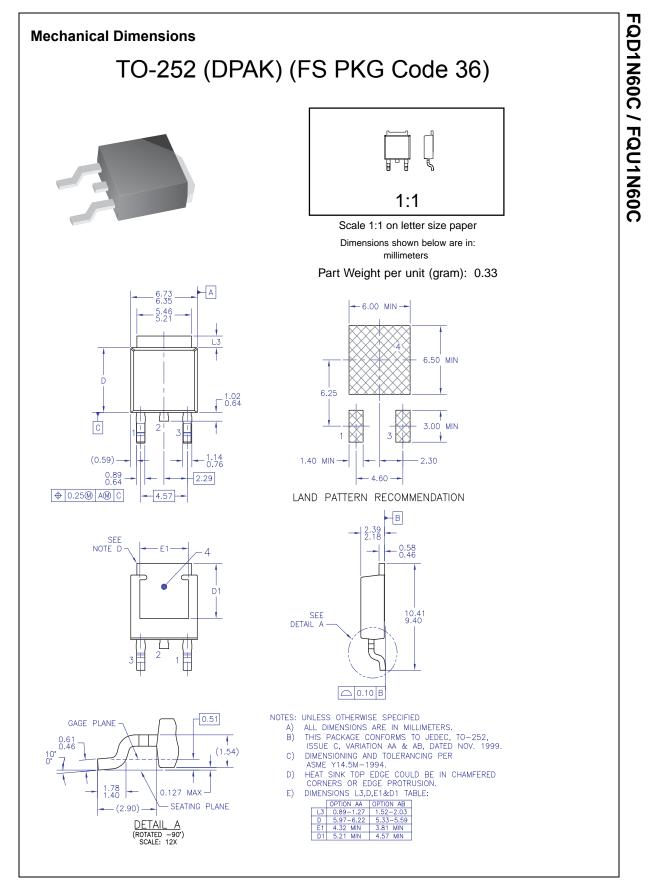




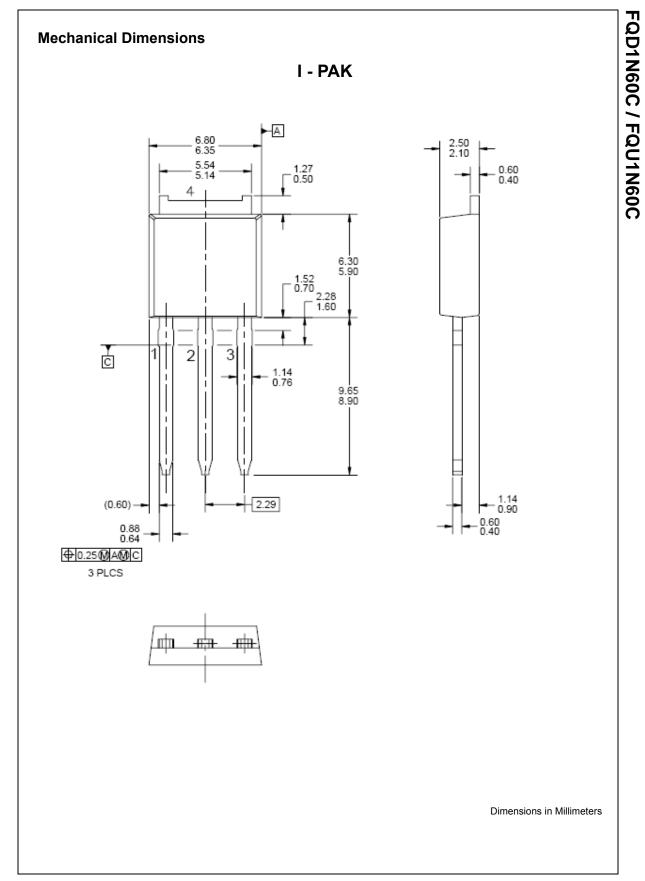




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